



# BGA2815

MMIC wideband amplifier

Rev. 5 — 29 May 2015

Product data sheet

## 1. Product profile

### 1.1 General description

Silicon Monolithic Microwave Integrated Circuit (MMIC) wideband amplifier with internal matching circuit in a 6-pin SOT363 plastic SMD package.

### 1.2 Features and benefits

- Input internally matched to  $50\ \Omega$
- A gain of 25.8 dB at 250 MHz decreasing to 24.7 dB at 2150 MHz
- Output power at 1 dB gain compression = 6 dBm
- Supply current = 18.2 mA at a supply voltage of 3.3 V
- Reverse isolation > 38 dB up to 2 GHz
- Good linearity with low second order and third order products
- Noise figure = 3.8 dB at 950 MHz
- Unconditionally stable ( $K > 1$ )
- No output inductor required

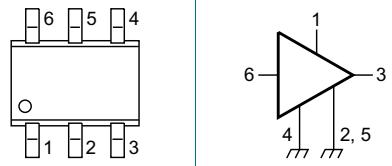
### 1.3 Applications

- LNB IF amplifiers
- General purpose low noise wideband amplifier for frequencies between DC and 2.2 GHz

## 2. Pinning information

Table 1. Pinning

| Pin  | Description     | Simplified outline | Graphic symbol |
|------|-----------------|--------------------|----------------|
| 1    | V <sub>CC</sub> |                    |                |
| 2, 5 | GND2            |                    |                |
| 3    | RF_OUT          |                    |                |
| 4    | GND1            |                    |                |
| 6    | RF_IN           |                    |                |



### 3. Ordering information

**Table 2. Ordering information**

| Type number | Package |  |  | Version |
|-------------|---------|--|--|---------|
|             | Name    | Description                              |  |         |
| BGA2815     | -       | plastic surface-mounted package; 6 leads |  | SOT363  |

### 4. Marking

**Table 3. Marking**

| Type number | Marking code | Description               |
|-------------|--------------|---------------------------|
| BGA2815     | *E9          | * = - : made in Hong Kong |
|             |              | * = p : made in Hong Kong |
|             |              | * = W : made in China     |
|             |              | * = t : made in Malaysia  |

### 5. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol             | Parameter               | Conditions              | Min  | Max  | Unit |
|--------------------|-------------------------|-------------------------|------|------|------|
| V <sub>CC</sub>    | supply voltage          | RF input AC coupled     | -0.5 | +5.0 | V    |
| I <sub>CC</sub>    | supply current          |                         | -    | 55   | mA   |
| P <sub>tot</sub>   | total power dissipation | T <sub>sp</sub> = 90 °C | -    | 200  | mW   |
| T <sub>stg</sub>   | storage temperature     |                         | -40  | +125 | °C   |
| T <sub>j</sub>     | junction temperature    |                         | -    | 125  | °C   |
| P <sub>drive</sub> | drive power             |                         | -    | 10   | dBm  |

### 6. Thermal characteristics

**Table 5. Thermal characteristics**

| Symbol                | Parameter  | Conditions   | Typ | Unit |
|-----------------------|--|--|-----|------|
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point | P <sub>tot</sub> = 200 mW; T <sub>sp</sub> = 90 °C | 300 | K/W  |

### 7. Characteristics

**Table 6. Characteristics**

V<sub>CC</sub> = 3.3 V; Z<sub>S</sub> = Z<sub>L</sub> = 50 Ω; P<sub>i</sub> = -40 dBm; T<sub>amb</sub> = 25 °C; measured on demo board; unless otherwise specified.

| Symbol          | Parameter      | Conditions | Min  | Typ  | Max  | Unit |
|-----------------|----------------|------------|------|------|------|------|
| V <sub>CC</sub> | supply voltage |            | 3.0  | 3.3  | 3.6  | V    |
| I <sub>CC</sub> | supply current |            | 15.7 | 18.2 | 21.1 | mA   |

**Table 6. Characteristics ...continued**

$V_{CC} = 3.3 \text{ V}$ ;  $Z_S = Z_L = 50 \Omega$ ;  $P_i = -40 \text{ dBm}$ ;  $T_{amb} = 25^\circ\text{C}$ ; measured on demo board; unless otherwise specified.

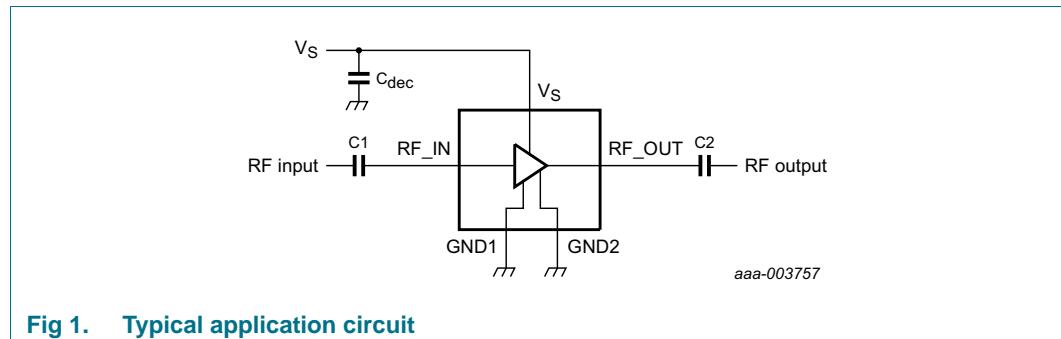
| Symbol       | Parameter                             | Conditions  | Min  | Typ  | Max  | Unit |
|--------------|---------------------------------------|---|------|------|------|------|
| $G_p$        | power gain                            | $f = 250 \text{ MHz}$                                 | 25.2 | 25.8 | 26.4 | dB   |
|              |                                       | $f = 950 \text{ MHz}$                                 | 24.6 | 25.3 | 26.0 | dB   |
|              |                                       | $f = 2150 \text{ MHz}$                                | 23.2 | 24.7 | 26.2 | dB   |
| $RL_{in}$    | input return loss                     | $f = 250 \text{ MHz}$                                 | 11   | 13   | 15   | dB   |
|              |                                       | $f = 950 \text{ MHz}$                                 | 11   | 13   | 15   | dB   |
|              |                                       | $f = 2150 \text{ MHz}$                                | 11   | 14   | 20   | dB   |
| $RL_{out}$   | output return loss                    | $f = 250 \text{ MHz}$                                 | 14   | 18   | 23   | dB   |
|              |                                       | $f = 950 \text{ MHz}$                                 | 15   | 16   | 17   | dB   |
|              |                                       | $f = 2150 \text{ MHz}$                                | 17   | 19   | 22   | dB   |
| $ISL$        | isolation                             | $f = 250 \text{ MHz}$                                 | 40   | 55   | 76   | dB   |
|              |                                       | $f = 950 \text{ MHz}$                                 | 43   | 45   | 46   | dB   |
|              |                                       | $f = 2150 \text{ MHz}$                                | 36   | 38   | 41   | dB   |
| $NF$         | noise figure                          | $f = 250 \text{ MHz}$                                 | 3.2  | 3.7  | 4.2  | dB   |
|              |                                       | $f = 950 \text{ MHz}$                                 | 3.4  | 3.8  | 4.3  | dB   |
|              |                                       | $f = 2150 \text{ MHz}$                                | 3.2  | 3.7  | 4.1  | dB   |
| $B_{-3dB}$   | -3 dB bandwidth                       | 3 dB below gain at 1 GHz                              | 2.8  | 3.0  | 3.1  | GHz  |
| $K$          | Rollett stability factor              | $f = 250 \text{ MHz}$                                 | 10   | 14   | 20   |      |
|              |                                       | $f = 950 \text{ MHz}$                                 | 3.5  | 4.5  | 6.5  |      |
|              |                                       | $f = 2150 \text{ MHz}$                                | 1.5  | 2    | 2.5  |      |
| $P_{L(sat)}$ | saturated output power                | $f = 250 \text{ MHz}$                                 | 7    | 8    | 8    | dBm  |
|              |                                       | $f = 950 \text{ MHz}$                                 | 3    | 5    | 6    | dBm  |
|              |                                       | $f = 2150 \text{ MHz}$                                | -1   | +1   | +2   | dBm  |
| $P_{L(1dB)}$ | output power at 1 dB gain compression | $f = 250 \text{ MHz}$                                 | 6    | 6    | 7    | dBm  |
|              |                                       | $f = 950 \text{ MHz}$                                 | 3    | 5    | 6    | dBm  |
|              |                                       | $f = 2150 \text{ MHz}$                                | -1   | +1   | +2   | dBm  |
| $IP3_I$      | input third-order intercept point     | $P_{drive} = -38 \text{ dBm}$ (for each tone)         |      |      |      |      |
|              |                                       | $f_1 = 250 \text{ MHz}; f_2 = 251 \text{ MHz}$        | -8   | -6   | -4   | dBm  |
|              |                                       | $f_1 = 950 \text{ MHz}; f_2 = 951 \text{ MHz}$        | -11  | -8   | -6   | dBm  |
|              |                                       | $f_1 = 2150 \text{ MHz}; f_2 = 2151 \text{ MHz}$      | -18  | -15  | -12  | dBm  |
| $IP3_O$      | output third-order intercept point    | $P_{drive} = -38 \text{ dBm}$ (for each tone)         |      |      |      |      |
|              |                                       | $f_1 = 250 \text{ MHz}; f_2 = 251 \text{ MHz}$        | 18   | 20   | 22   | dBm  |
|              |                                       | $f_1 = 950 \text{ MHz}; f_2 = 951 \text{ MHz}$        | 15.5 | 17.5 | 19.5 | dBm  |
|              |                                       | $f_1 = 2150 \text{ MHz}; f_2 = 2151 \text{ MHz}$      | 7.5  | 10.5 | 13.5 | dBm  |
| $P_{L(2H)}$  | second harmonic output power          | $P_{drive} = -35 \text{ dBm}$                         |      |      |      |      |
|              |                                       | $f_{1H} = 250 \text{ MHz}; f_{2H} = 500 \text{ MHz}$  | -54  | -52  | -50  | dBm  |
|              |                                       | $f_{1H} = 950 \text{ MHz}; f_{2H} = 1900 \text{ MHz}$ | -46  | -44  | -43  | dBm  |
| $\Delta IM2$ | second-order intermodulation distance | $P_{drive} = -38 \text{ dBm}$ (for each tone)         |      |      |      |      |
|              |                                       | $f_1 = 250 \text{ MHz}; f_2 = 251 \text{ MHz}$        | 42   | 53   | 64   | dBc  |
|              |                                       | $f_1 = 950 \text{ MHz}; f_2 = 951 \text{ MHz}$        | 39   | 51   | 62   | dBc  |

## 8. Application information

[Figure 1](#) shows a typical application circuit for the BGA2815 MMIC. The device is internally matched to  $50\ \Omega$  and therefore does not need any external matching. The value of the input and output DC blocking capacitors C2 and C3 should not be more than  $100\ pF$  for applications above  $100\ MHz$ . However, when the device is operated below  $100\ MHz$ , the capacitor value should be increased.

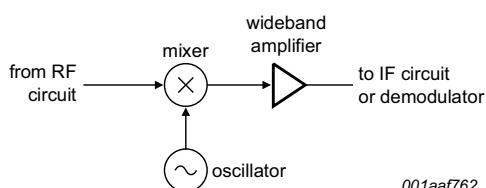
The location of the  $470\ pF$  supply decoupling capacitor ( $C_{dec}$ ) can be precisely chosen for optimum performance.

The PCB top ground plane, connected to pins 2, 4 and 5 must be as close as possible to the MMIC, preferably also below the MMIC. When using via holes, use multiple via holes as close as possible to the MMIC.



[Fig 1. Typical application circuit](#)

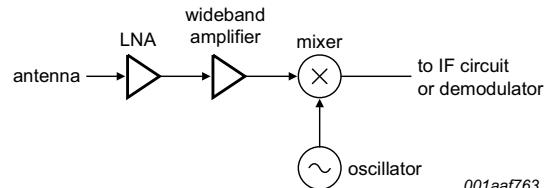
### 8.1 Application examples



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The MMIC is very suitable as IF amplifier in e.g. LNB's. The excellent wideband characteristics make it an easy building block.

[Fig 2. Application as IF amplifier](#)

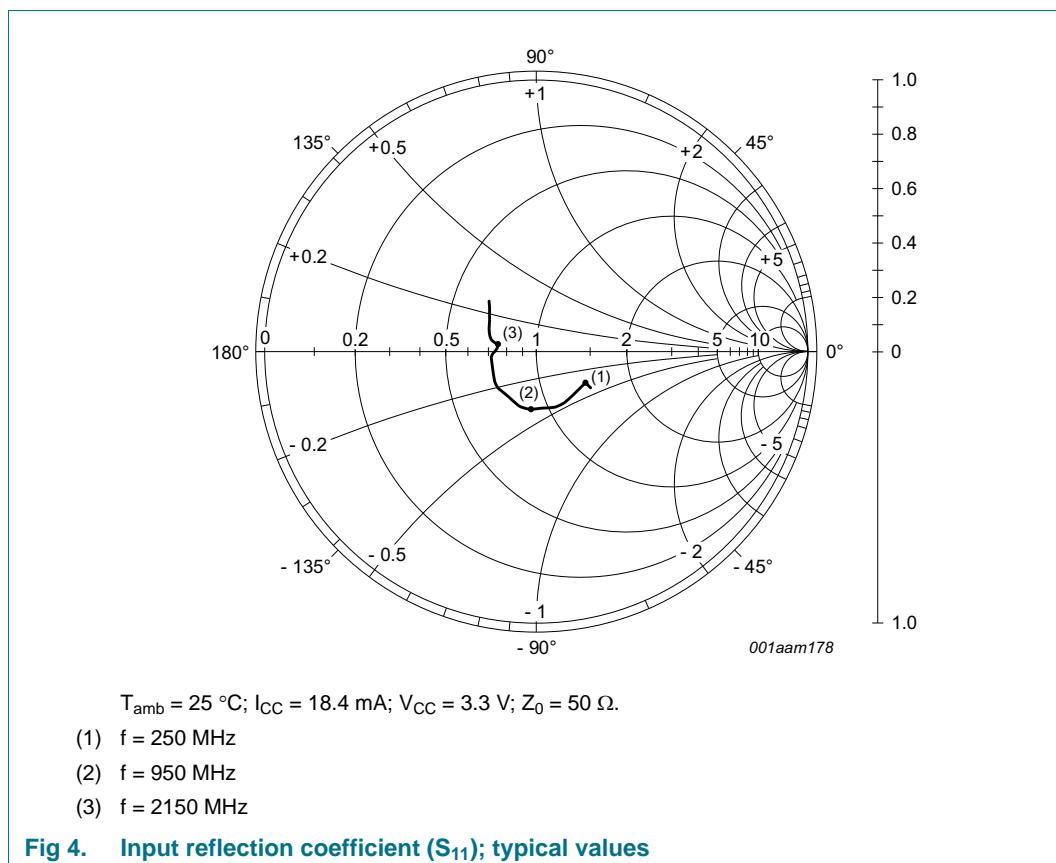


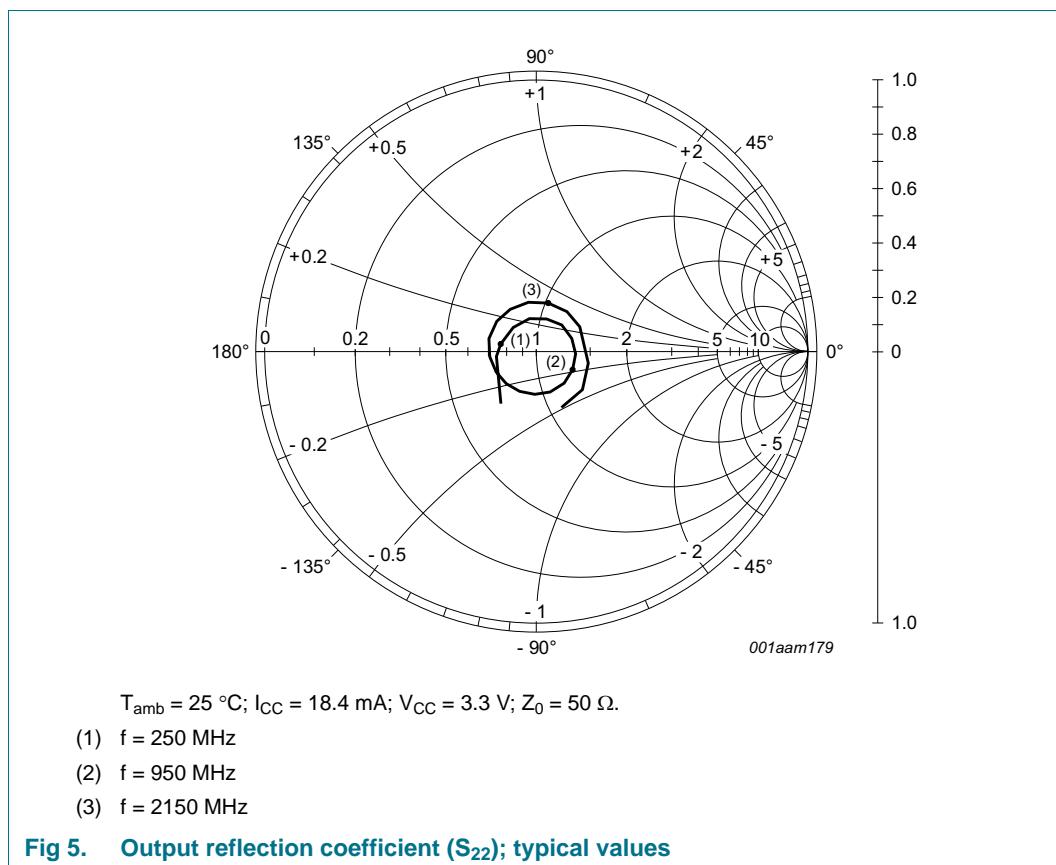
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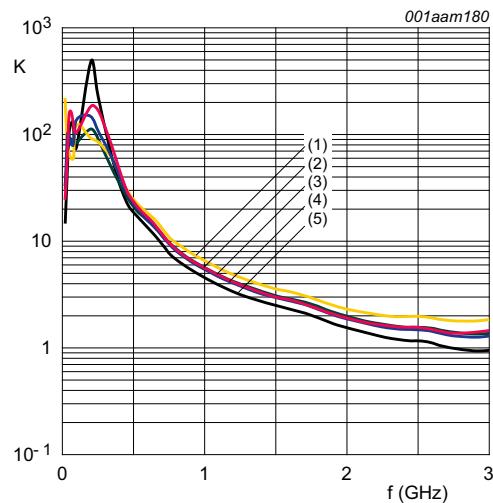
As second amplifier after an LNA, the MMIC offers an easy matching, low noise solution.

[Fig 3. Application as RF amplifier](#)

## 8.2 Graphs

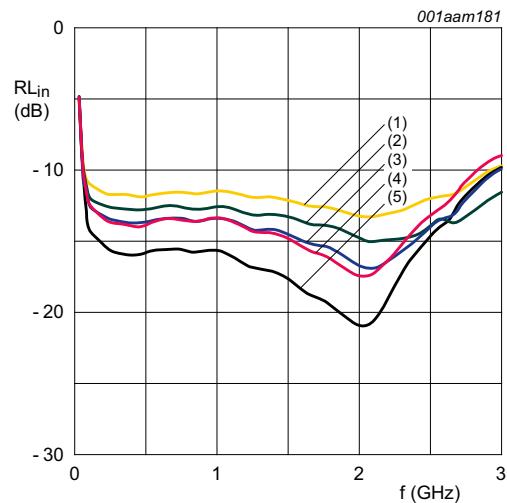






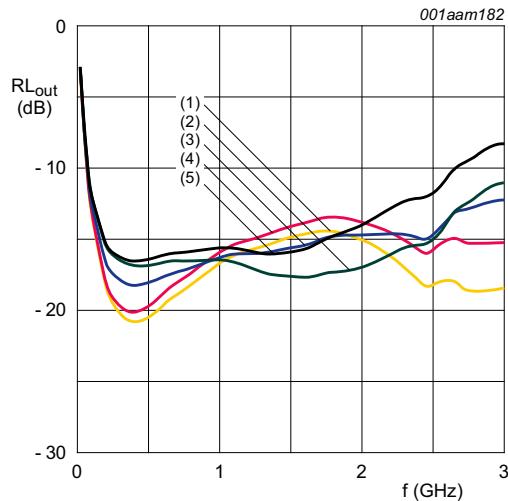
- $P_{\text{drive}} = -40 \text{ dBm}; Z_0 = 50 \Omega.$
- (1)  $V_{\text{CC}} = 3.0 \text{ V}; T_{\text{amb}} = 85^\circ\text{C}; I_{\text{CC}} = 15.93 \text{ mA}.$
  - (2)  $V_{\text{CC}} = 3.0 \text{ V}; T_{\text{amb}} = -40^\circ\text{C}; I_{\text{CC}} = 16.12 \text{ mA}.$
  - (3)  $V_{\text{CC}} = 3.3 \text{ V}; T_{\text{amb}} = 25^\circ\text{C}; I_{\text{CC}} = 18.41 \text{ mA}.$
  - (4)  $V_{\text{CC}} = 3.6 \text{ V}; T_{\text{amb}} = 85^\circ\text{C}; I_{\text{CC}} = 20.11 \text{ mA}.$
  - (5)  $V_{\text{CC}} = 3.6 \text{ V}; T_{\text{amb}} = -40^\circ\text{C}; I_{\text{CC}} = 20.23 \text{ mA}.$

**Fig 6. Rollett stability factor as function of frequency; typical values**



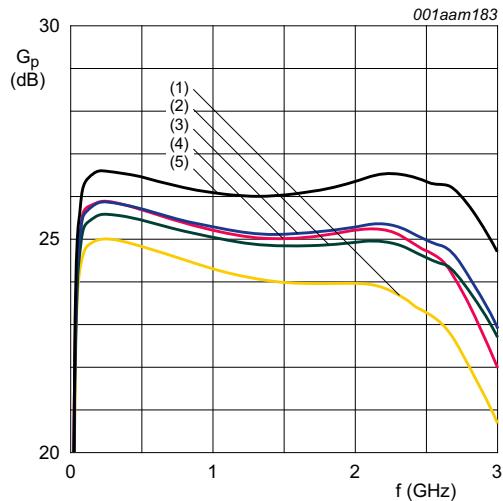
- $P_{\text{drive}} = -40 \text{ dBm}; Z_0 = 50 \Omega.$
- (1)  $V_{\text{CC}} = 3.0 \text{ V}; T_{\text{amb}} = 85^\circ\text{C}; I_{\text{CC}} = 15.93 \text{ mA}.$
  - (2)  $V_{\text{CC}} = 3.0 \text{ V}; T_{\text{amb}} = -40^\circ\text{C}; I_{\text{CC}} = 16.12 \text{ mA}.$
  - (3)  $V_{\text{CC}} = 3.3 \text{ V}; T_{\text{amb}} = 25^\circ\text{C}; I_{\text{CC}} = 18.41 \text{ mA}.$
  - (4)  $V_{\text{CC}} = 3.6 \text{ V}; T_{\text{amb}} = 85^\circ\text{C}; I_{\text{CC}} = 20.11 \text{ mA}.$
  - (5)  $V_{\text{CC}} = 3.6 \text{ V}; T_{\text{amb}} = -40^\circ\text{C}; I_{\text{CC}} = 20.23 \text{ mA}.$

**Fig 7. Input return loss as function of frequency; typical values**



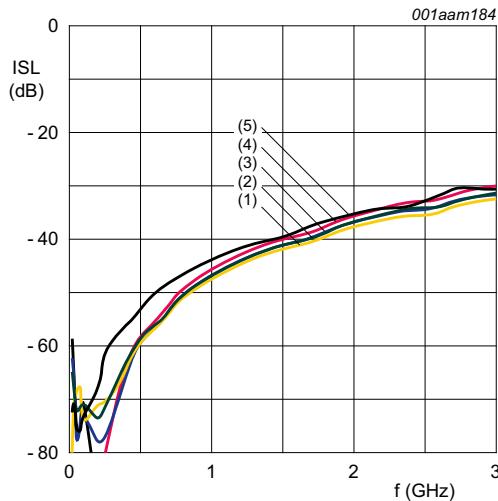
- $P_{\text{drive}} = -40 \text{ dBm}; Z_0 = 50 \Omega.$
- (1)  $V_{\text{CC}} = 3.0 \text{ V}; T_{\text{amb}} = 85^\circ\text{C}; I_{\text{CC}} = 15.93 \text{ mA}.$
  - (2)  $V_{\text{CC}} = 3.0 \text{ V}; T_{\text{amb}} = -40^\circ\text{C}; I_{\text{CC}} = 16.12 \text{ mA}.$
  - (3)  $V_{\text{CC}} = 3.3 \text{ V}; T_{\text{amb}} = 25^\circ\text{C}; I_{\text{CC}} = 18.41 \text{ mA}.$
  - (4)  $V_{\text{CC}} = 3.6 \text{ V}; T_{\text{amb}} = 85^\circ\text{C}; I_{\text{CC}} = 20.11 \text{ mA}.$
  - (5)  $V_{\text{CC}} = 3.6 \text{ V}; T_{\text{amb}} = -40^\circ\text{C}; I_{\text{CC}} = 20.23 \text{ mA}.$

**Fig 8. Output return loss as function of frequency; typical values**



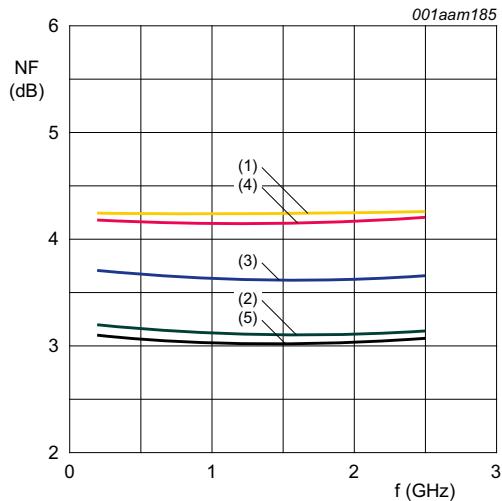
- $P_{\text{drive}} = -40 \text{ dBm}; Z_0 = 50 \Omega.$
- (1)  $V_{\text{CC}} = 3.0 \text{ V}; T_{\text{amb}} = 85^\circ\text{C}; I_{\text{CC}} = 15.93 \text{ mA}.$
  - (2)  $V_{\text{CC}} = 3.0 \text{ V}; T_{\text{amb}} = -40^\circ\text{C}; I_{\text{CC}} = 16.12 \text{ mA}.$
  - (3)  $V_{\text{CC}} = 3.3 \text{ V}; T_{\text{amb}} = 25^\circ\text{C}; I_{\text{CC}} = 18.41 \text{ mA}.$
  - (4)  $V_{\text{CC}} = 3.6 \text{ V}; T_{\text{amb}} = 85^\circ\text{C}; I_{\text{CC}} = 20.11 \text{ mA}.$
  - (5)  $V_{\text{CC}} = 3.6 \text{ V}; T_{\text{amb}} = -40^\circ\text{C}; I_{\text{CC}} = 20.23 \text{ mA}.$

**Fig 9. Power gain as function of frequency; typical values**



- $P_{\text{drive}} = -40 \text{ dBm}$ ;  $Z_0 = 50 \Omega$ .
- (1)  $V_{\text{CC}} = 3.0 \text{ V}$ ;  $T_{\text{amb}} = 85^\circ\text{C}$ ;  $I_{\text{CC}} = 15.93 \text{ mA}$ .
  - (2)  $V_{\text{CC}} = 3.0 \text{ V}$ ;  $T_{\text{amb}} = -40^\circ\text{C}$ ;  $I_{\text{CC}} = 16.12 \text{ mA}$ .
  - (3)  $V_{\text{CC}} = 3.3 \text{ V}$ ;  $T_{\text{amb}} = 25^\circ\text{C}$ ;  $I_{\text{CC}} = 18.41 \text{ mA}$ .
  - (4)  $V_{\text{CC}} = 3.6 \text{ V}$ ;  $T_{\text{amb}} = 85^\circ\text{C}$ ;  $I_{\text{CC}} = 20.11 \text{ mA}$ .
  - (5)  $V_{\text{CC}} = 3.6 \text{ V}$ ;  $T_{\text{amb}} = -40^\circ\text{C}$ ;  $I_{\text{CC}} = 20.23 \text{ mA}$ .

**Fig 10. Isolation as function of frequency; typical values**



- $Z_0 = 50 \Omega$ .
- (1)  $V_{\text{CC}} = 3.0 \text{ V}$ ;  $T_{\text{amb}} = 85^\circ\text{C}$ ;  $I_{\text{CC}} = 15.93 \text{ mA}$ .
  - (2)  $V_{\text{CC}} = 3.0 \text{ V}$ ;  $T_{\text{amb}} = -40^\circ\text{C}$ ;  $I_{\text{CC}} = 16.12 \text{ mA}$ .
  - (3)  $V_{\text{CC}} = 3.3 \text{ V}$ ;  $T_{\text{amb}} = 25^\circ\text{C}$ ;  $I_{\text{CC}} = 18.41 \text{ mA}$ .
  - (4)  $V_{\text{CC}} = 3.6 \text{ V}$ ;  $T_{\text{amb}} = 85^\circ\text{C}$ ;  $I_{\text{CC}} = 20.11 \text{ mA}$ .
  - (5)  $V_{\text{CC}} = 3.6 \text{ V}$ ;  $T_{\text{amb}} = -40^\circ\text{C}$ ;  $I_{\text{CC}} = 20.23 \text{ mA}$ .

**Fig 11. Noise figure as function of frequency; typical values**

### 8.3 Tables

**Table 7. Supply current over temperature and supply voltages**  
Typical values.

| Symbol          | Parameter      | Conditions              | T <sub>amb</sub> (°C) |       |       | Unit |
|-----------------|----------------|-------------------------|-----------------------|-------|-------|------|
|                 |                |                         | -40                   | +25   | +85   |      |
| I <sub>CC</sub> | supply current | V <sub>CC</sub> = 3.0 V | 16.12                 | 16.34 | 15.93 | mA   |
|                 |                | V <sub>CC</sub> = 3.3 V | 18.76                 | 18.41 | 17.95 | mA   |
|                 |                | V <sub>CC</sub> = 3.6 V | 20.23                 | 19.91 | 20.11 | mA   |

**Table 8. Second harmonic output power over temperature and supply voltages**  
Typical values.

| Symbol             | Parameter                    | Conditions                                | T <sub>amb</sub> (°C) |     |     | Unit |
|--------------------|------------------------------|---|-----------------------|-----|-----|------|
|                    |                              |   | -40                   | +25 | +85 |      |
| P <sub>L(2H)</sub> | second harmonic output power | f = 250 MHz; P <sub>drive</sub> = -35 dBm |                       |     |     |      |
|                    |                              | V <sub>CC</sub> = 3.0 V                   | -49                   | -51 | -53 | dBm  |
|                    |                              | V <sub>CC</sub> = 3.3 V                   | -51                   | -53 | -54 | dBm  |
|                    |                              | V <sub>CC</sub> = 3.6 V                   | -52                   | -54 | -55 | dBm  |
|                    |                              | f = 950 MHz; P <sub>drive</sub> = -35 dBm |                       |     |     |      |
|                    |                              | V <sub>CC</sub> = 3.0 V                   | -43                   | -44 | -45 | dBm  |
|                    |                              | V <sub>CC</sub> = 3.3 V                   | -43                   | -44 | -45 | dBm  |
|                    |                              | V <sub>CC</sub> = 3.6 V                   | -43                   | -44 | -45 | dBm  |

**Table 9. Input power at 1 dB gain compression over temperature and supply voltages**  
*Typical values.*

| <b>Symbol</b> | <b>Parameter</b>                     | <b>Conditions</b>        | <b>T<sub>amb</sub> (°C)</b> |            |            | <b>Unit</b> |
|---------------|--------------------------------------|--------------------------|-----------------------------|------------|------------|-------------|
|               |                                      |                          | <b>-40</b>                  | <b>+25</b> | <b>+85</b> |             |
| $P_{i(1dB)}$  | input power at 1 dB gain compression | $f = 250 \text{ MHz}$    |                             |            |            |             |
|               |                                      | $V_{CC} = 3.0 \text{ V}$ | -19                         | -19        | -19        | dBm         |
|               |                                      | $V_{CC} = 3.3 \text{ V}$ | -18                         | -18        | -19        | dBm         |
|               |                                      | $V_{CC} = 3.6 \text{ V}$ | -18                         | -18        | -18        | dBm         |
|               |                                      | $f = 950 \text{ MHz}$    |                             |            |            |             |
|               |                                      | $V_{CC} = 3.0 \text{ V}$ | -19                         | -20        | -20        | dBm         |
|               |                                      | $V_{CC} = 3.3 \text{ V}$ | -19                         | -19        | -20        | dBm         |
|               |                                      | $V_{CC} = 3.6 \text{ V}$ | -19                         | -19        | -20        | dBm         |
|               |                                      | $f = 2150 \text{ MHz}$   |                             |            |            |             |
|               |                                      | $V_{CC} = 3.0 \text{ V}$ | -22                         | -23        | -24        | dBm         |
|               |                                      | $V_{CC} = 3.3 \text{ V}$ | -23                         | -23        | -24        | dBm         |
|               |                                      | $V_{CC} = 3.6 \text{ V}$ | -23                         | -23        | -24        | dBm         |

**Table 10. Output power at 1 dB gain compression over temperature and supply voltages**  
*Typical values.*

| <b>Symbol</b> | <b>Parameter</b>                      | <b>Conditions</b>        | <b>T<sub>amb</sub> (°C)</b> |            |            | <b>Unit</b> |
|---------------|---------------------------------------|--------------------------|-----------------------------|------------|------------|-------------|
|               |                                       |                          | <b>-40</b>                  | <b>+25</b> | <b>+85</b> |             |
| $P_{L(1dB)}$  | output power at 1 dB gain compression | $f = 250 \text{ MHz}$    |                             |            |            |             |
|               |                                       | $V_{CC} = 3.0 \text{ V}$ | 6                           | 6          | 5          | dBm         |
|               |                                       | $V_{CC} = 3.3 \text{ V}$ | 7                           | 7          | 6          | dBm         |
|               |                                       | $V_{CC} = 3.6 \text{ V}$ | 8                           | 7          | 6          | dBm         |
|               |                                       | $f = 950 \text{ MHz}$    |                             |            |            |             |
|               |                                       | $V_{CC} = 3.0 \text{ V}$ | 5                           | 4          | 3          | dBm         |
|               |                                       | $V_{CC} = 3.3 \text{ V}$ | 5                           | 5          | 4          | dBm         |
|               |                                       | $V_{CC} = 3.6 \text{ V}$ | 6                           | 5          | 4          | dBm         |
|               |                                       | $f = 2150 \text{ MHz}$   |                             |            |            |             |
|               |                                       | $V_{CC} = 3.0 \text{ V}$ | +2                          | 0          | -2         | dBm         |
|               |                                       | $V_{CC} = 3.3 \text{ V}$ | +2                          | +1         | -1         | dBm         |
|               |                                       | $V_{CC} = 3.6 \text{ V}$ | 3                           | 1          | 0          | dBm         |

**Table 11. Saturated output power over temperature and supply voltages**  
*Typical values.*

| Symbol              | Parameter              | Conditions              | T <sub>amb</sub> (°C) |     |     | Unit |
|---------------------|------------------------|-------------------------|-----------------------|-----|-----|------|
|                     |                        |                         | -40                   | +25 | +85 |      |
| P <sub>L(sat)</sub> | saturated output power | f = 250 MHz             |                       |     |     |      |
|                     |                        | V <sub>CC</sub> = 3.0 V | 7                     | 7   | 7   | dBm  |
|                     |                        | V <sub>CC</sub> = 3.3 V | 8                     | 8   | 7   | dBm  |
|                     |                        | V <sub>CC</sub> = 3.6 V | 9                     | 9   | 8   | dBm  |
|                     |                        | f = 950 MHz             |                       |     |     |      |
|                     |                        | V <sub>CC</sub> = 3.0 V | 5                     | 4   | 3   | dBm  |
|                     |                        | V <sub>CC</sub> = 3.3 V | 5                     | 5   | 4   | dBm  |
|                     |                        | V <sub>CC</sub> = 3.6 V | 6                     | 5   | 4   | dBm  |
|                     |                        | f = 2150 MHz            |                       |     |     |      |
|                     |                        | V <sub>CC</sub> = 3.0 V | +2                    | +1  | -1  | dBm  |
|                     |                        | V <sub>CC</sub> = 3.3 V | +3                    | +1  | -1  | dBm  |
|                     |                        | V <sub>CC</sub> = 3.6 V | 3                     | 2   | 0   | dBm  |

**Table 12. Second-order intermodulation distance over temperature and supply voltages**  
*Typical values.*

| Symbol             | Parameter                             | Conditions   | T <sub>amb</sub> (°C) |     |     | Unit |
|--------------------|---------------------------------------|--|-----------------------|-----|-----|------|
|                    |                                       |  | -40                   | +25 | +85 |      |
| $\Delta\text{IM}2$ | second-order intermodulation distance | $f_1 = 250 \text{ MHz};$<br>$f_2 = 251 \text{ MHz};$<br>$P_{\text{drive}} = -38 \text{ dBm}$ |                       |     |     |      |
|                    |                                       | V <sub>CC</sub> = 3.0 V  | 43                    | 47  | 51  | dBc  |
|                    |                                       | V <sub>CC</sub> = 3.3 V  | 50                    | 55  | 58  | dBc  |
|                    |                                       | V <sub>CC</sub> = 3.6 V  | 58                    | 62  | 57  | dBc  |
|                    |                                       | $f_1 = 950 \text{ MHz};$<br>$f_2 = 951 \text{ MHz};$<br>$P_{\text{drive}} = -38 \text{ dBm}$ |                       |     |     |      |
|                    |                                       | V <sub>CC</sub> = 3.0 V  | 41                    | 44  | 49  | dBc  |
|                    |                                       | V <sub>CC</sub> = 3.3 V  | 49                    | 53  | 60  | dBc  |
|                    |                                       | V <sub>CC</sub> = 3.6 V  | 58                    | 64  | 56  | dBc  |

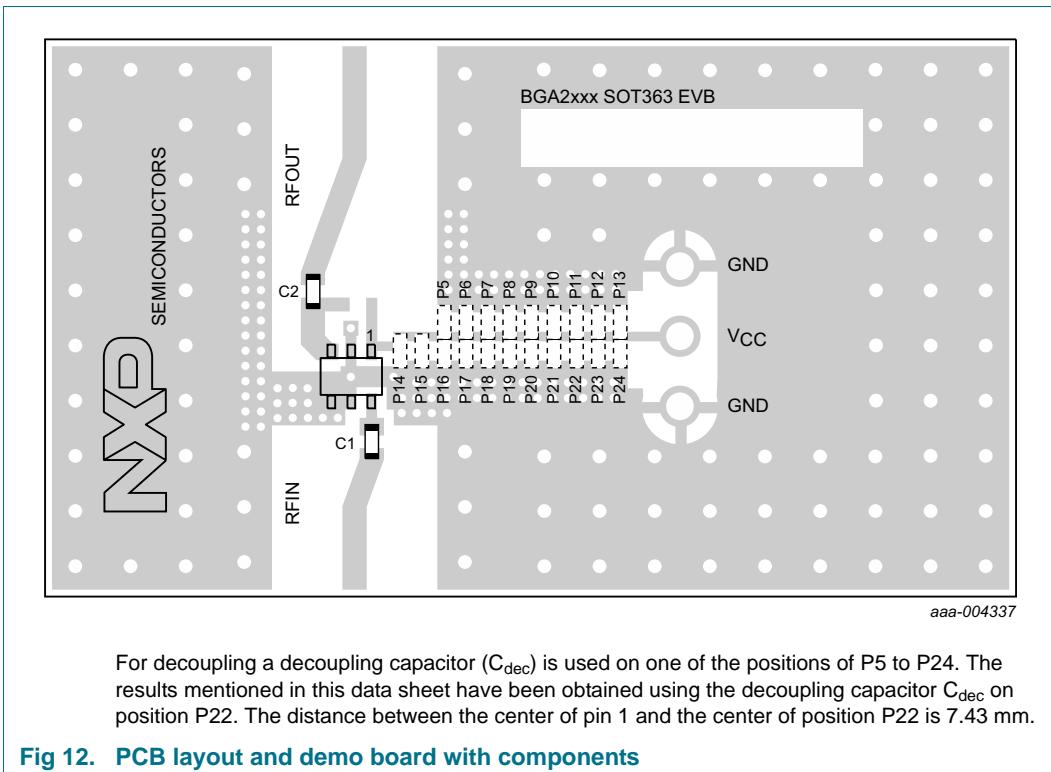
**Table 13. Output third-order intercept point over temperature and supply voltages**  
*Typical values.*

| <b>Symbol</b>    | <b>Parameter</b>                   | <b>Conditions</b>   | <b>T<sub>amb</sub> (°C)</b> |            |            | <b>Unit</b> |
|------------------|------------------------------------|---|-----------------------------|------------|------------|-------------|
|                  |                                    |   | <b>-40</b>                  | <b>+25</b> | <b>+85</b> |             |
| IP <sub>3O</sub> | output third-order intercept point | f <sub>1</sub> = 250 MHz; f <sub>2</sub> = 251 MHz;<br>P <sub>drive</sub> = -38 dBm   |                             |            |            |             |
|                  |                                    | V <sub>CC</sub> = 3.0 V   | 18                          | 20         | 18         | dBm         |
|                  |                                    | V <sub>CC</sub> = 3.3 V   | 20                          | 20         | 19         | dBm         |
|                  |                                    | V <sub>CC</sub> = 3.6 V   | 23                          | 21         | 20         | dBm         |
|                  |                                    | f <sub>1</sub> = 950 MHz; f <sub>2</sub> = 951 MHz;<br>P <sub>drive</sub> = -38 dBm   |                             |            |            |             |
|                  |                                    | V <sub>CC</sub> = 3.0 V   | 18                          | 16         | 14         | dBm         |
|                  |                                    | V <sub>CC</sub> = 3.3 V   | 18.5                        | 17.5       | 15.5       | dBm         |
|                  |                                    | V <sub>CC</sub> = 3.6 V   | 20                          | 19         | 17         | dBm         |
|                  |                                    | f <sub>1</sub> = 2150 MHz; f <sub>2</sub> = 2151 MHz;<br>P <sub>drive</sub> = -38 dBm |                             |            |            |             |
|                  |                                    | V <sub>CC</sub> = 3.0 V   | 12                          | 10         | 8          | dBm         |
|                  |                                    | V <sub>CC</sub> = 3.3 V   | 11.5                        | 10.5       | 7.5        | dBm         |
|                  |                                    | V <sub>CC</sub> = 3.6 V   | 13                          | 11         | 8          | dBm         |

**Table 14. -3 dB bandwidth over temperature and supply voltages**  
*Typical values.*

| <b>Symbol</b>     | <b>Parameter</b> | <b>Conditions</b>       | <b>T<sub>amb</sub> (°C)</b> |            |            | <b>Unit</b> |
|-------------------|------------------|-------------------------|-----------------------------|------------|------------|-------------|
|                   |                  |                         | <b>-40</b>                  | <b>+25</b> | <b>+85</b> |             |
| B <sub>-3dB</sub> | -3 dB bandwidth  | V <sub>CC</sub> = 3.0 V | 2.985                       | 2.917      | 2.812      | GHz         |
|                   |                  | V <sub>CC</sub> = 3.3 V | 3.062                       | 2.965      | 2.857      | GHz         |
|                   |                  | V <sub>CC</sub> = 3.6 V | 3.119                       | 2.994      | 2.875      | GHz         |

## 9. Test information



For decoupling a decoupling capacitor ( $C_{dec}$ ) is used on one of the positions of P5 to P24. The results mentioned in this data sheet have been obtained using the decoupling capacitor  $C_{dec}$  on position P22. The distance between the center of pin 1 and the center of position P22 is 7.43 mm.

**Fig 12. PCB layout and demo board with components**

**Table 15. List of components used for the typical application**

| Component     | Description  | Value  | Dimensions | Remarks                     |
|---------------|--|--------|------------|-----------------------------|
| C1, C2        | multilayer ceramic chip capacitor                        | 470 pF | 0603       | X7R RF coupling capacitor   |
| P5 to P24 [1] | position for multilayer ceramic chip capacitor $C_{dec}$ | 470 pF | 0603       | X7R RF decoupling capacitor |
| IC1           | BGA2815 MMIC   | -      | SOT363     |                             |

- [1] For decoupling a decoupling capacitor ( $C_{dec}$ ) is used on one of the positions of P5 to P24. The results mentioned in this data sheet have been obtained using the decoupling capacitor  $C_{dec}$  on position P22.

## 10. Package outline

Plastic surface-mounted package; 6 leads

SOT363

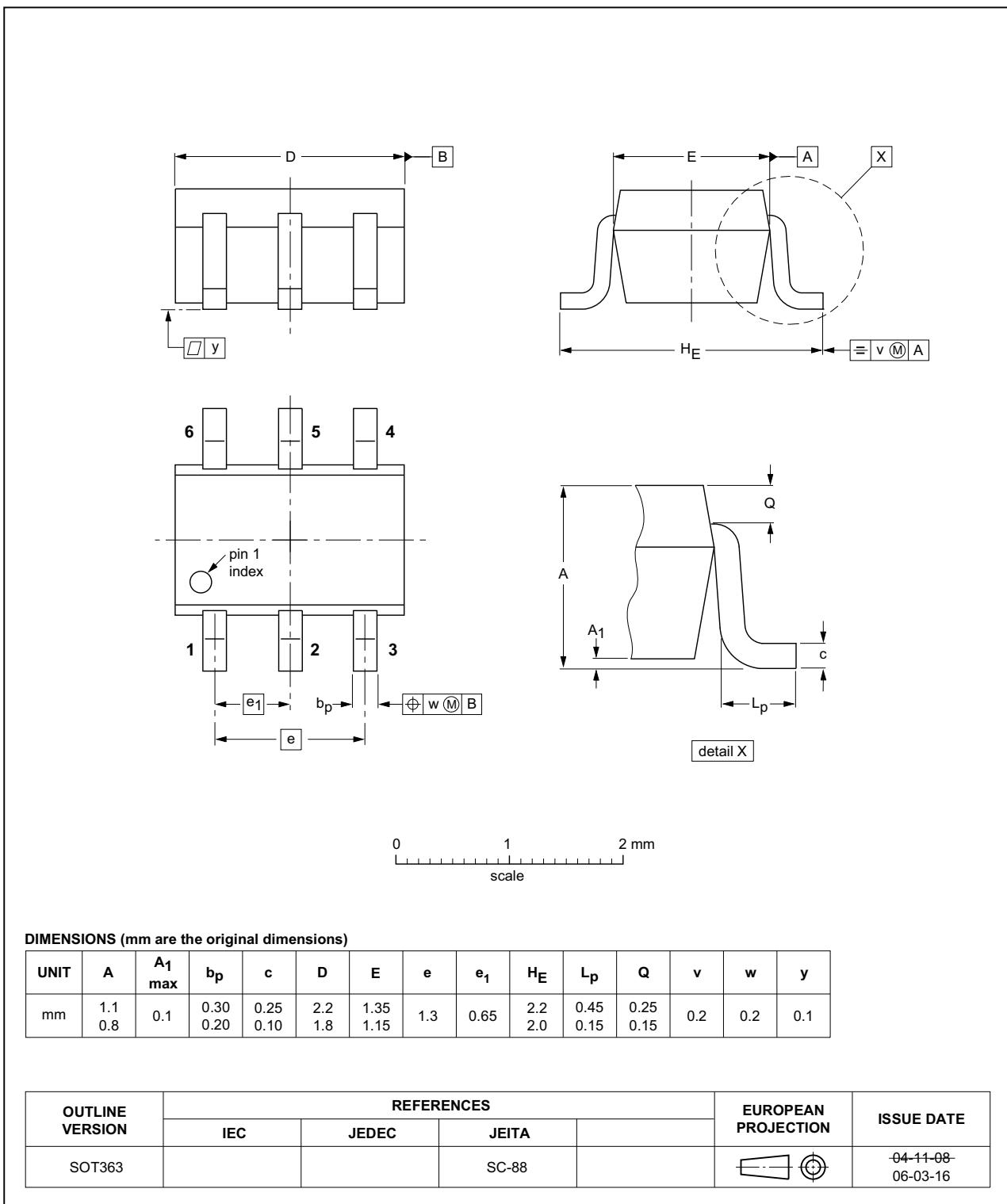


Fig 13. Package outline SOT363

## 11. Abbreviations

**Table 16. Abbreviations**

| Acronym | Description               |
|---------|---------------------------|
| IF      | Intermediate Frequency    |
| LNA     | Low-Noise Amplifier       |
| LNB     | Low-Noise Block converter |
| PCB     | Printed-Circuit Board     |

## 12. Revision history

**Table 17. Revision history**

| Document ID   | Release date   | Data sheet status  | Change notice | Supersedes  |
|---------------|--|--------------------|---------------|-------------|
| BGA2815 v.5   | 20150529   | Product data sheet | -             | BGA2815 v.4 |
| Modifications | • <a href="#">Table 4 on page 2</a> : the maximum value for $P_{drive}$ has been changed to 10 dBm |                    |               |             |
| BGA2815 v.4   | 20141209   | Product data sheet | -             | BGA2815 v.3 |
| BGA2815 v.3   | 20130905   | Product data sheet | -             | BGA2815 v.2 |
| BGA2815 v.2   | 20101019   | Product data sheet | -             | BGA2815 v.1 |
| BGA2815 v.1   | 20100625   | Product data sheet | -             | -           |

## 13. Legal information

### 13.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 29 May 2015

Document identifier: BGA2815